

Vishay Siliconix

Dual P-Channel 1.8-V (G-S) MOSFET

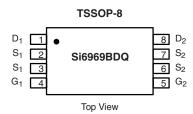
PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
	0.030 at V _{GS} = - 4.5 V	- 4.6		
- 12	0.040 at V _{GS} = - 2.5 V	- 3.8		
	0.055 at V _{GS} = - 1.8 V	- 3.0		

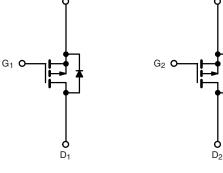
FEATURES

- Halogen-free Option Available
- TrenchFET[®] Power MOSFETs

S₁







Ordering Information: Si6969BDQ-T1 Si6969BDQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

P-Channel MOSFET

 S_2

ABSOLUTE MAXIMUM RATINGS	A = 25 °C, unle	ss otherwise r	noted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 12		V	
Gate-Source Voltage		V _{GS}	± 8			
	T _A = 25 °C	- I _D	- 4.6	- 4.0		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 3.8	- 3.2	٨	
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	- 30		A	
Continuous Source Current (Diode Conduction) ^a		ا _S	- 1.0	- 0.7		
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	1.14	0.83	W	
	T _A = 70 °C		0.73	0.53		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	R _{thJA}	88	110	
Maximum Junction-to-Ambient ^a	Steady State		120	150	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	65	80	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

* Pb containing terminations are not RoHS compliant, exemptions may apply.

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SPECIFICATIONS $T_J = 25^{\circ}$	C, unless o	otherwise noted					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 0.45		- 0.8	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -9.6 V, V_{GS} = 0 V$		- 1			
		$V_{DS} = -9.6 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			- 25	μA	
On-State Drain Current ^a	I _{D(on)}	V _{DS} - 8 V, V _{GS} = - 4.5 V	- 30			А	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -4.6 \text{ A}$		0.024	0.030	40 Ω	
		$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -3.8 \text{ A}$		0.031	0.040		
		V _{GS} = - 1.8 V, I _D = - 3.0 A		0.044	0.055		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 8 V, I _D = - 4.6 A		18		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.25 A, V _{GS} = 0 V		- 0.68	- 1.1	V	
Dynamic ^b							
Total Gate Charge	Qg			16.5	25		
Gate-Source Charge	Q _{gs}	V_{DS} = - 6 V, V_{GS} = - 4.5 V, I_D = - 4.6 A		2		nC	
Gate-Drain Charge	Q _{gd}			4.7		1	
Turn-On Delay Time	t _{d(on)}			20	40		
Rise Time	t _r	V_{DD} = - 6 V, R_L = 6 Ω		35	60		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1.0 A, V_GEN = - 4.5 V, R_G = 6 Ω		110	180	ns	
Fall Time	t _f			90	150		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.25 A, dl/dt = 100 A/μs		100	200		

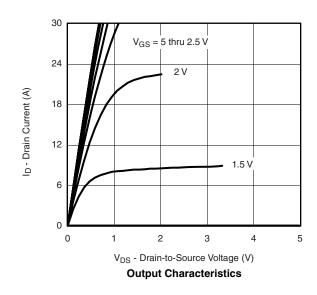
Notes:

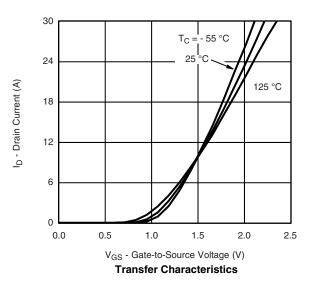
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

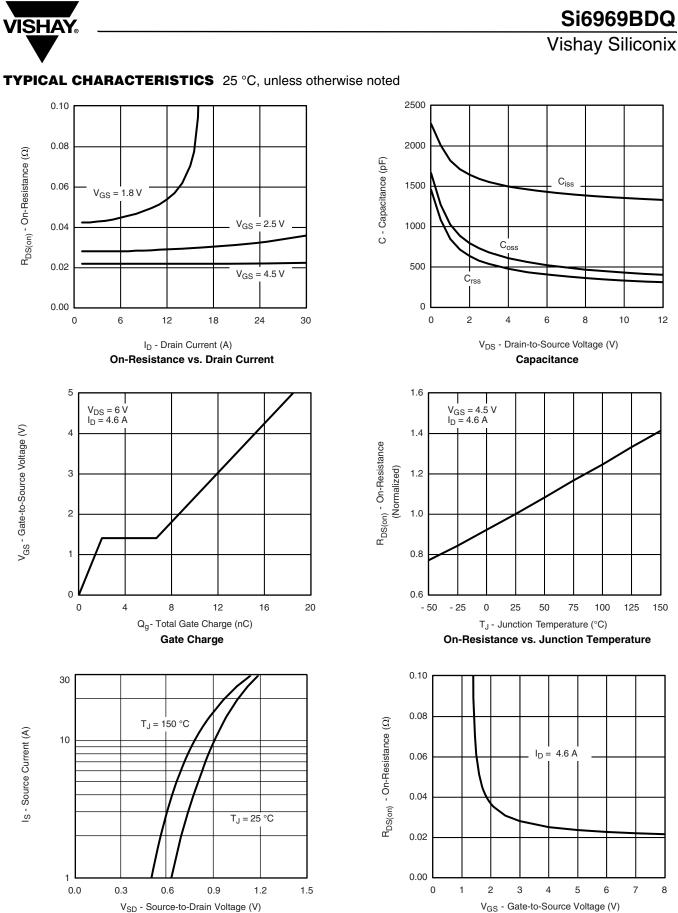
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







Source-Drain Diode Forward Voltage

Document Number: 72017 S-81221-Rev. C, 02-Jun-08 On-Resistance vs. Gate-to-Source Voltage

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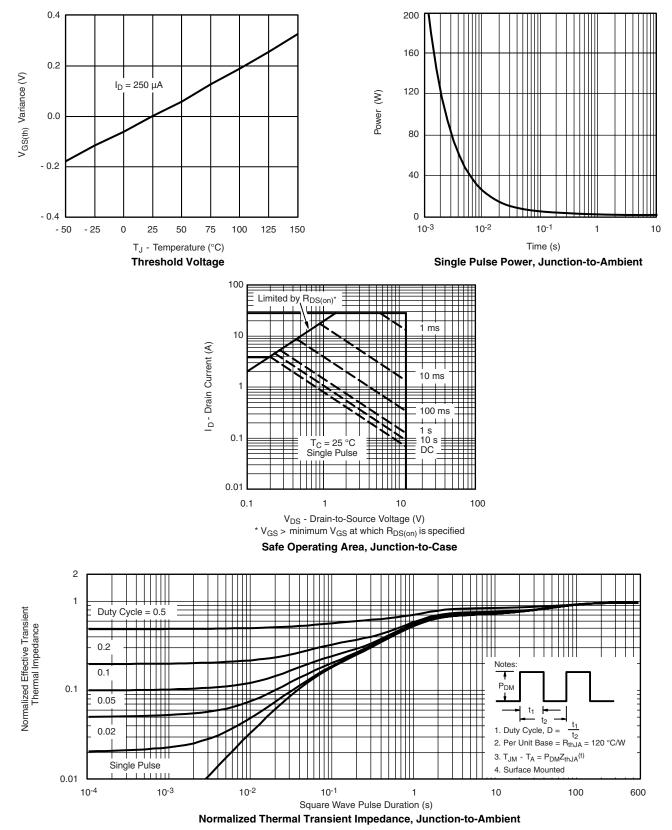
12

150

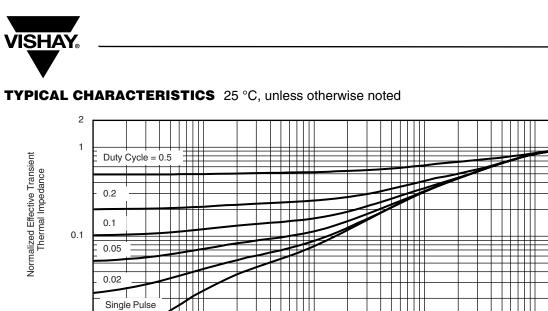
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







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Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Foot

10-1

1

10-2

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72017.

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Si6969BDQ

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